

APPLICATION NOTE

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SUBJECT: RD01MUS2 & RD07MUS2B RF characteristics data at f=400-470MHz, Vdd=7.2V

SUMMARY:

This application note shows the RF wide band characteristics data
(Frequency, Pout vs. Pin, Pout vs. Vgg characteristics) at 400 to 470 MHz band.

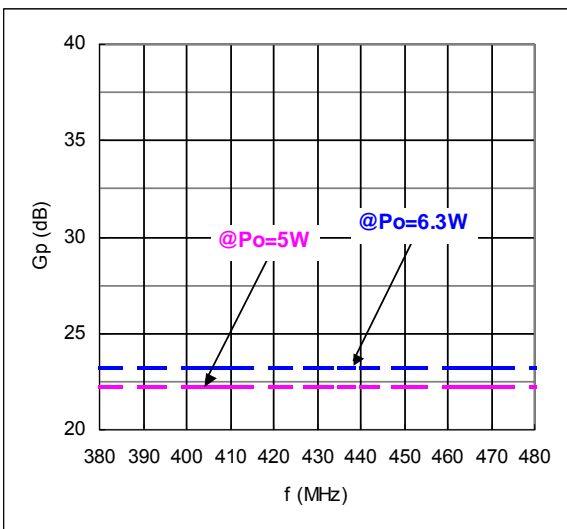
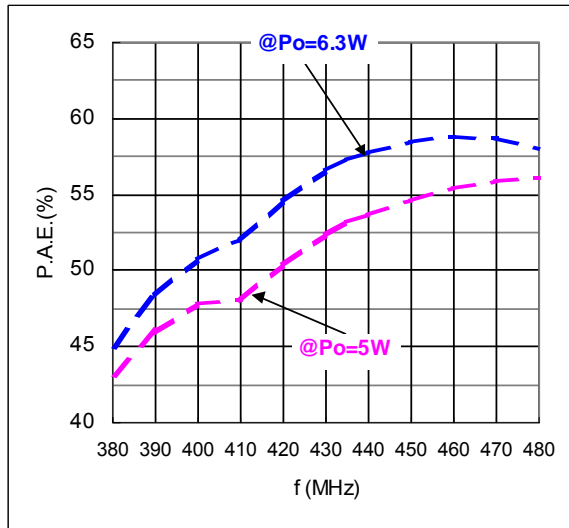
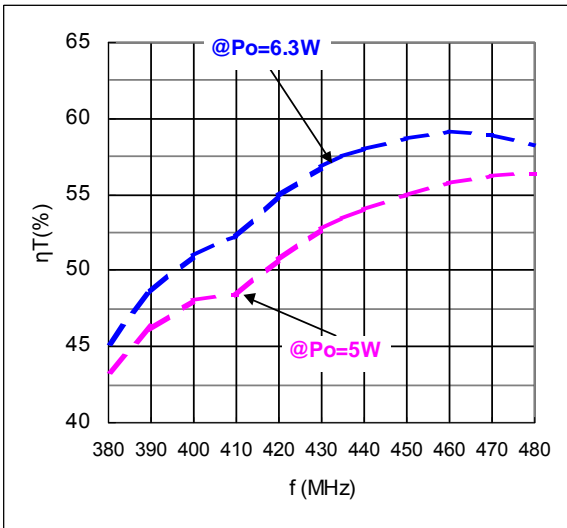
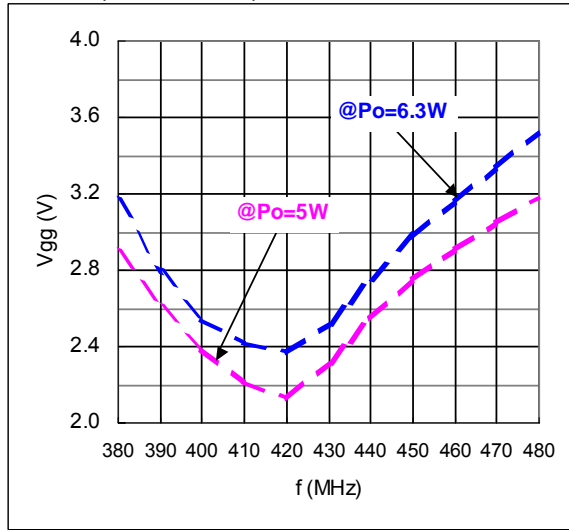
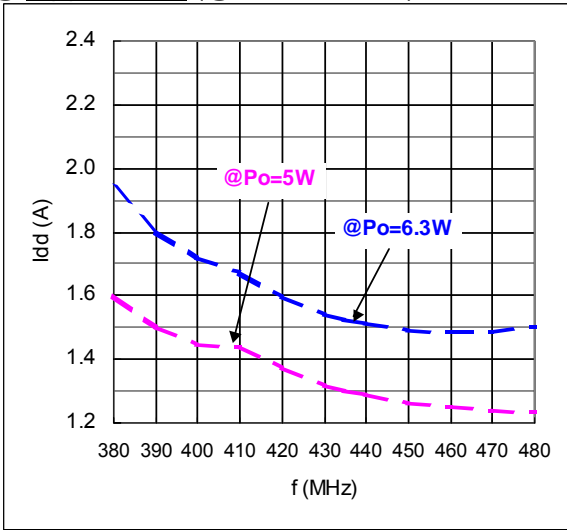
- Sample history :
 - RD01MUS2 : Lot number "571"
 - RD07MUS2B : Lot number "086ZE-G"

- Evaluate conditions :
 - @f=400 to 470MHz : Vdd=7.2V, Vgg=3.5V

- Results :
 - Page 2-5. shows the typical Frequency characteristics data.
 - Page 6-9. shows the typical Pout vs. Pin characteristics data.
 - Page 10-13. shows the typical Pout vs. Vgg characteristics data.
 - Page 14-15. shows the equivalent circuit.

Frequency characteristics 1

@ **V_{gg} Control** (@P_o=6.3W, 5W), V_{dd}=7.2V, P_i=30mW (=14.77dBm)



Frequency characteristics 1 data

@ Po=6.3W, Vdd=7.2V, Pi=30mW (=14.77dBm)

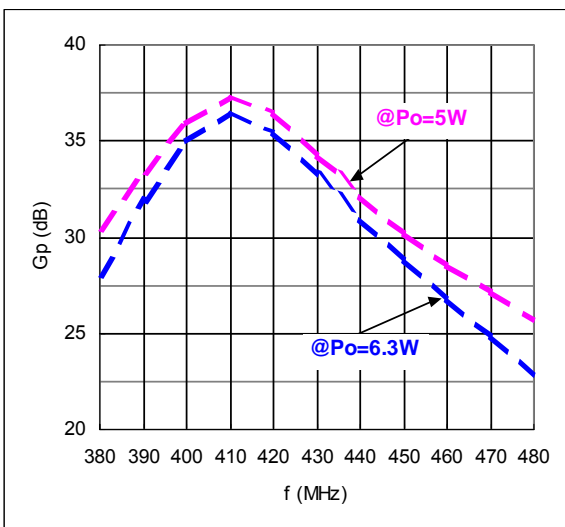
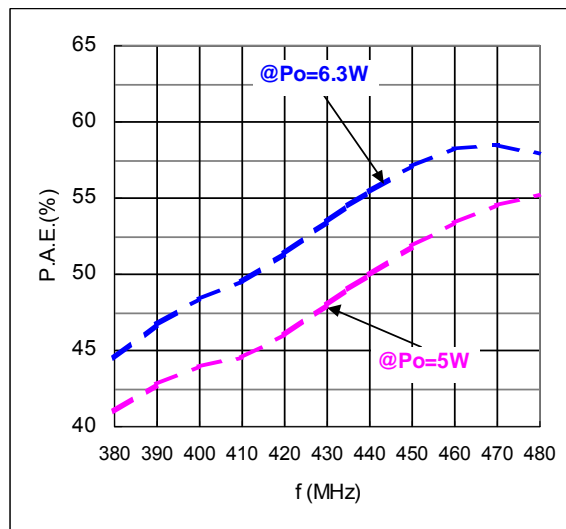
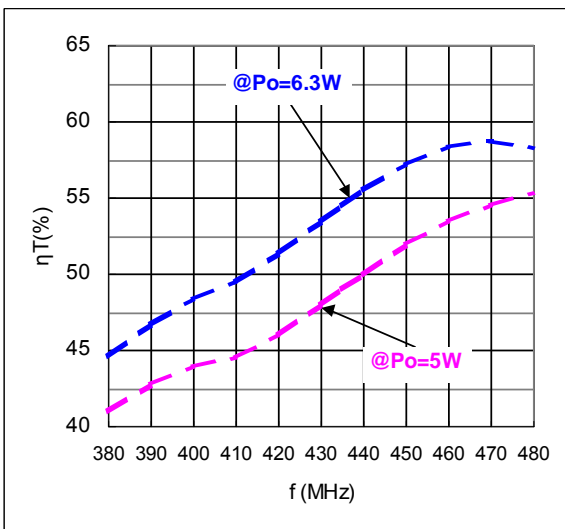
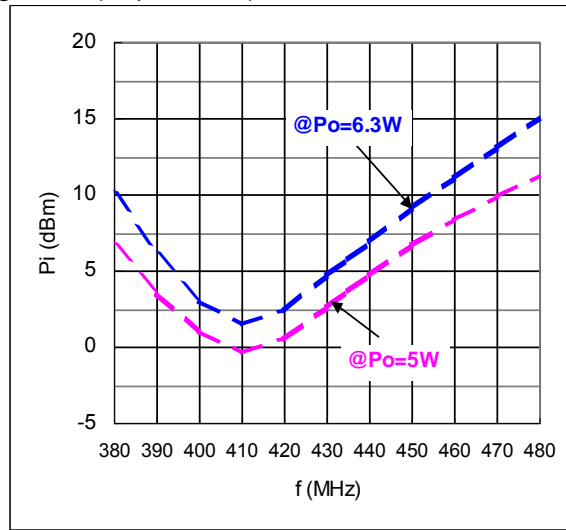
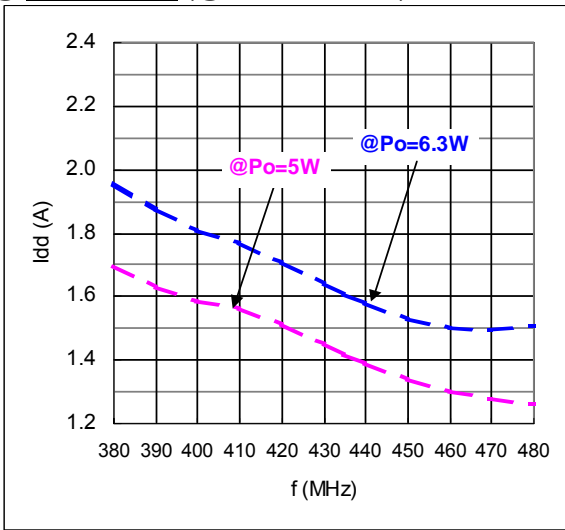
f (MHz)	V _{gg} (V)	G _p (dB)	I _{dd} (A)	η _T (%)	P.A.E. (%)	2fo (dBc)	3fo (dBc)
380	3.17	23.2	1.94	45.2	45.0	-20	-62
390	2.79	23.2	1.80	48.6	48.4	-19	-64
400	2.54	23.2	1.72	51.0	50.7	-20	-65
410	2.42	23.2	1.68	52.2	52.0	-24	-66
420	2.38	23.2	1.60	54.9	54.7	-30	-67
430	2.52	23.2	1.54	56.8	56.6	-35	-65
435	2.64	23.2	1.52	57.5	57.3	-38	-65
440	2.75	23.2	1.51	58.0	57.7	-40	-64
450	2.98	23.2	1.49	58.7	58.5	-44	-63
460	3.16	23.2	1.48	59.1	58.9	-48	-64
470	3.34	23.2	1.49	59.0	58.7	-50	-64
480	3.52	23.2	1.50	58.2	58.0	-50	-69

@ Po=5W, Vdd=7.2V, Pi=30mW (=14.77dBm)

f (MHz)	V _{gg} (V)	G _p (dB)	I _{dd} (A)	η _T (%)	P.A.E. (%)	2fo (dBc)	3fo (dBc)
380	2.90	22.2	1.60	43.4	43.2	-15	-62
390	2.61	22.2	1.50	46.2	45.9	-15	-64
400	2.39	22.2	1.45	48.1	47.8	-15	-64
410	2.21	22.2	1.44	48.4	48.1	-19	-68
420	2.13	22.2	1.37	50.8	50.5	-25	-69
430	2.32	22.2	1.32	52.7	52.4	-30	-66
435	2.43	22.2	1.30	53.5	53.2	-33	-67
440	2.55	22.2	1.29	54.0	53.7	-35	-65
450	2.75	22.2	1.26	54.9	54.6	-40	-64
460	2.92	22.2	1.25	55.8	55.4	-45	-64
470	3.05	22.2	1.24	56.2	55.9	-50	-64
480	3.18	22.2	1.24	56.4	56.1	-55	-68

Frequency characteristics 2

@ Pin Control (@Po=6.3W, 5W), Vdd=7.2V, Vgg=3.5V (Idq=404mA)



Frequency characteristics 2 data

@ Po=6.3W, Vdd=7.2V, Vgg=3.5V (Idq=404mA)

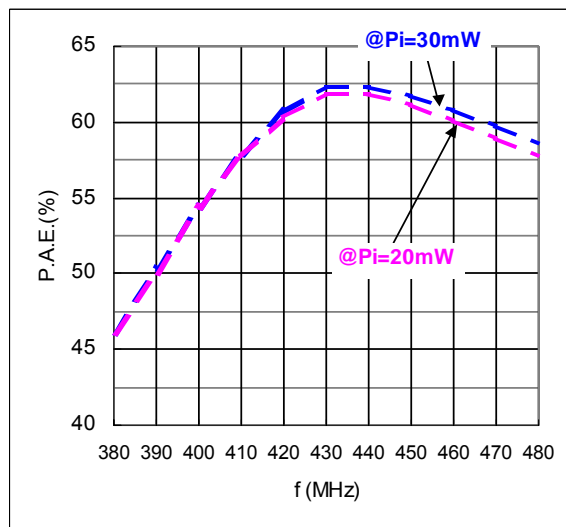
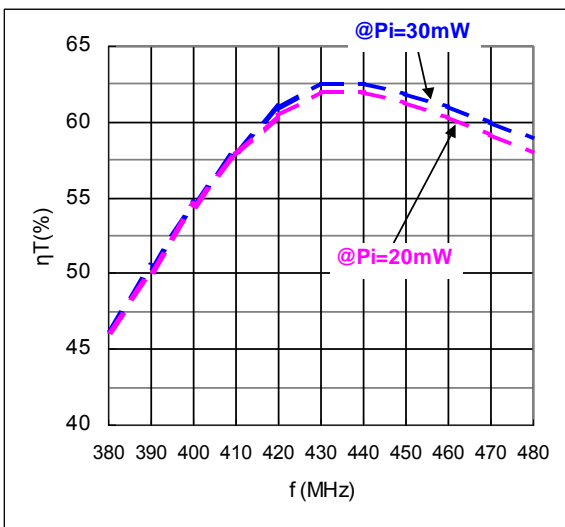
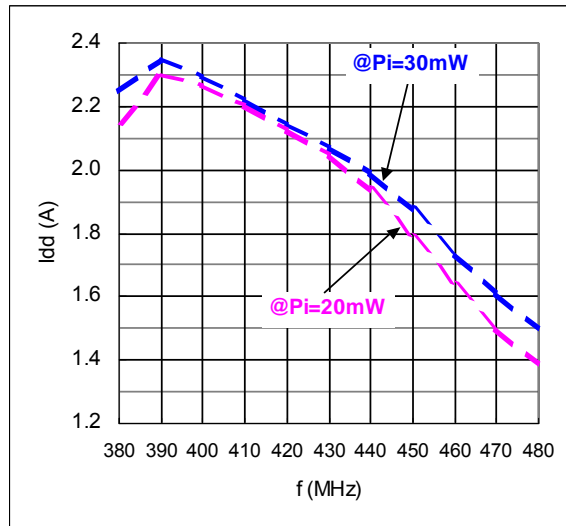
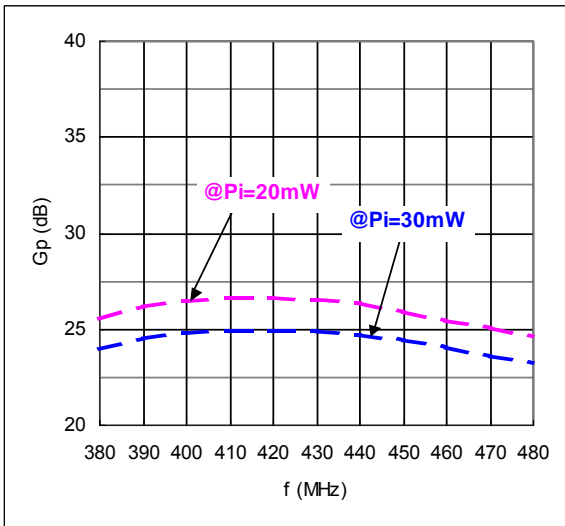
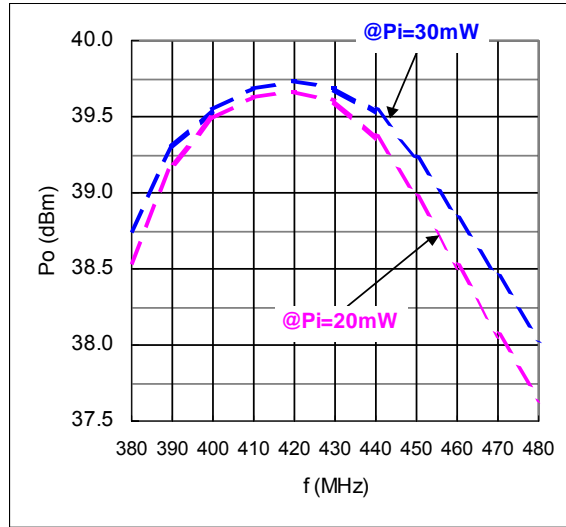
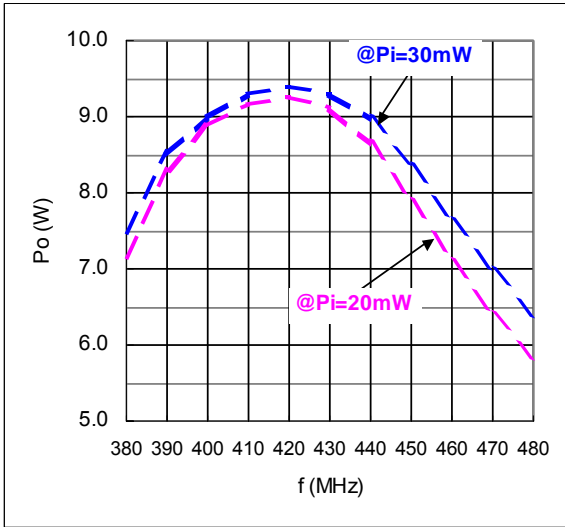
f (MHz)	Pi (W)	Pi (dBm)	Gp (dB)	Idd (A)	η_T (%)	P.A.E. (%)	2fo (dBc)	3fo (dBc)
380	0.010	10.0	28.0	1.96	44.6	44.5	-22	-64
390	0.004	6.07	31.9	1.87	46.7	46.7	-24	-64
400	0.002	3.01	35.0	1.81	48.4	48.4	-26	-66
410	0.001	1.54	36.5	1.77	49.6	49.6	-31	-67
420	0.002	2.49	35.5	1.71	51.4	51.4	-36	-67
430	0.003	4.76	33.2	1.64	53.5	53.5	-40	-67
435	0.004	5.87	32.1	1.61	54.5	54.5	-42	-66
440	0.005	7.02	31.0	1.58	55.5	55.5	-43	-65
450	0.008	9.16	28.8	1.53	57.2	57.1	-46	-63
460	0.013	11.2	26.8	1.50	58.3	58.2	-48	-64
470	0.020	13.1	24.9	1.49	58.7	58.5	-49	-65
480	0.033	15.1	22.9	1.51	58.2	57.9	-50	-69

@ Po=5W, Vdd=7.2V, Vgg=3.5V (Idq=404mA)

f (MHz)	Pi (W)	Pi (dBm)	Gp (dB)	Idd (A)	η_T (%)	P.A.E. (%)	2fo (dBc)	3fo (dBc)
380	0.005	6.58	30.4	1.69	41.1	41.1	-19	-64
390	0.002	3.60	33.4	1.63	42.8	42.7	-20	-65
400	0.001	1.01	36.0	1.58	43.9	43.9	-20	-66
410	0.001	-0.36	37.4	1.56	44.5	44.5	-25	-68
420	0.001	0.53	36.5	1.51	46.1	46.1	-30	-69
430	0.002	2.71	34.3	1.45	48.0	48.0	-35	-67
435	0.002	3.74	33.3	1.42	49.1	49.1	-37	-67
440	0.003	4.81	32.2	1.39	50.1	50.0	-40	-66
450	0.005	6.73	30.3	1.34	52.0	51.9	-44	-64
460	0.007	8.40	28.6	1.30	53.5	53.4	-48	-64
470	0.010	9.86	27.1	1.28	54.6	54.5	-52	-66
480	0.013	11.3	25.8	1.26	55.3	55.2	-55	-67

Frequency characteristics 3

@ Pin Control (@Pi=30mW, 20mW), Vdd=7.2V, Vgg=3.5V (Idq=404mA)



Frequency characteristics 3 data

@ **Pi=30mW**, Vdd=7.2V, Vgg=3.5V (Idq=404mA)

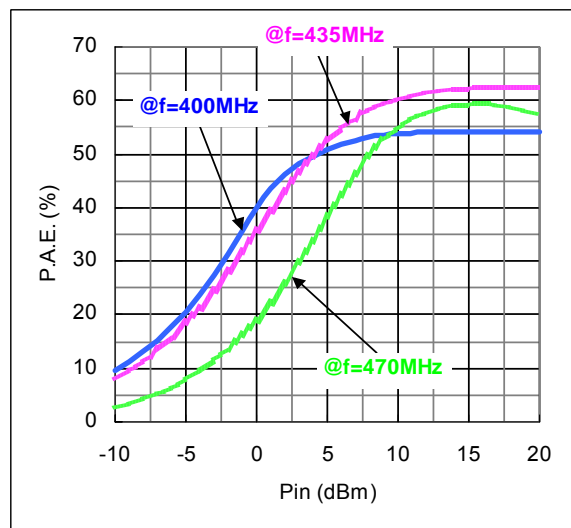
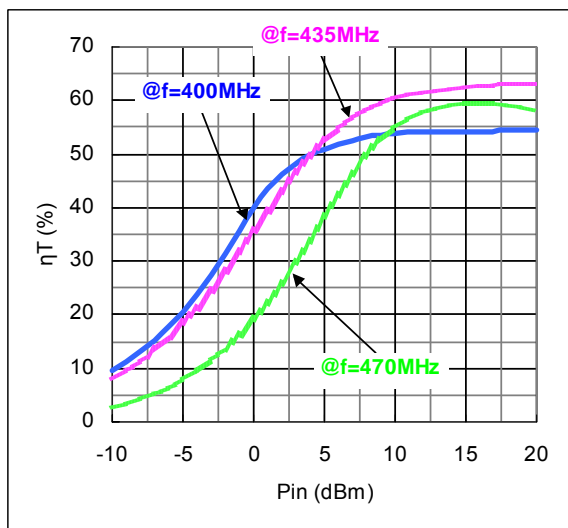
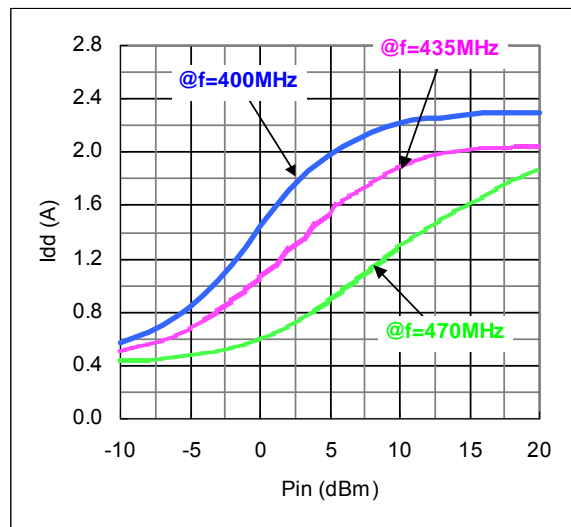
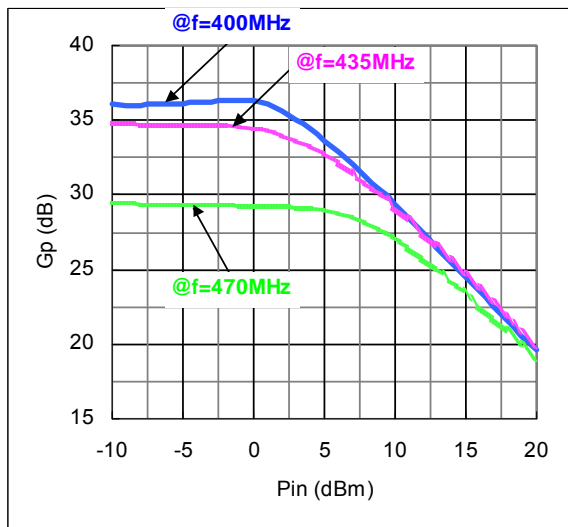
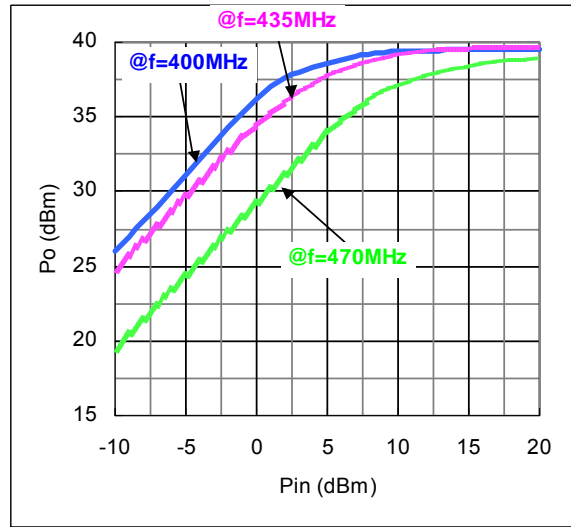
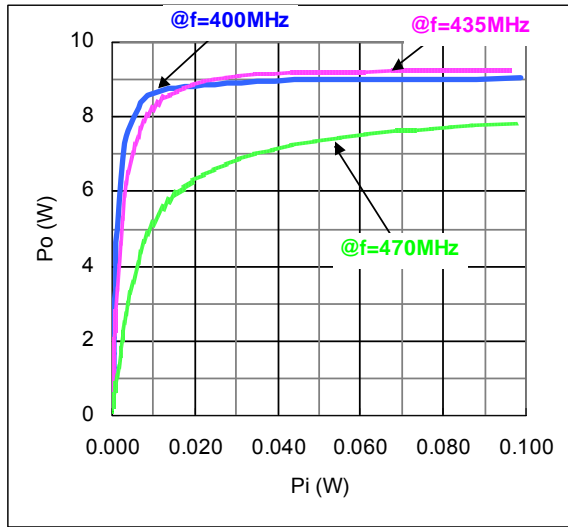
f (MHz)	Po (W)	Po (dBm)	Gp (dB)	Idd (A)	η_T (%)	P.A.E. (%)	2fo (dBc)	3fo (dBc)
380	7.49	38.7	24.0	2.25	46.3	46.1	-22	-62
390	8.52	39.3	24.5	2.35	50.4	50.3	-24	-63
400	9.01	39.5	24.8	2.29	54.6	54.4	-26	-63
410	9.29	39.7	24.9	2.22	58.1	57.9	-31	-63
420	9.39	39.7	24.9	2.14	60.9	60.7	-35	<-65
430	9.31	39.7	24.9	2.07	62.5	62.3	-38	-64
440	8.98	39.5	24.7	1.99	62.6	62.3	-40	-64
450	8.36	39.2	24.4	1.88	61.9	61.7	-43	-63
460	7.63	38.8	24.1	1.74	61.1	60.8	-46	<-65
470	6.98	38.4	23.6	1.62	60.0	59.7	-48	<-65
480	6.37	38.0	23.3	1.50	58.9	58.6	-51	<-65

@ **Pi=20mW**, Vdd=7.2V, Vgg=3.5V (Idq=404mA)

f (MHz)	Po (W)	Po (dBm)	Gp (dB)	Idd (A)	η_T (%)	P.A.E. (%)	2fo (dBc)	3fo (dBc)
380	7.13	38.5	25.5	2.15	46.2	46.0	-22	<-65
390	8.31	39.2	26.2	2.30	50.2	50.1	-24	-63
400	8.89	39.5	26.5	2.27	54.4	54.3	-27	-64
410	9.17	39.6	26.6	2.20	57.8	57.7	-31	<-65
420	9.26	39.7	26.7	2.13	60.5	60.3	-35	<-65
430	9.13	39.6	26.6	2.05	62.0	61.8	-38	<-65
440	8.64	39.4	26.3	1.94	62.0	61.9	-41	-64
450	7.87	39.0	25.9	1.78	61.3	61.1	-44	-63
460	7.09	38.5	25.5	1.63	60.3	60.1	-47	<-65
470	6.40	38.1	25.0	1.50	59.2	59.0	-50	<-65
480	5.81	37.6	24.6	1.39	57.9	57.7	-53	<-65

Pout vs. Pin characteristics

@ Vdd=7.2V, Vgg=3.5V (Idq=404mA), f=400MHz, 435MHz, 470MHz



Pout vs. Pin characteristics data

@ f=400MHz, Vgg=3.5V (Idq=404mA)

Vdd (V)	Pi (W)	Pi (dBm)	Po (W)	Po (dBm)	Gp (dB)	Idd (A)	η_T (%)	P.A.E. (%)
7.47	0.000	-10.0	0.40	26.0	36.0	0.57	9.4	9.4
7.47	0.000	-9.0	0.50	27.0	36.0	0.61	11.1	11.1
7.46	0.000	-8.0	0.63	28.0	36.0	0.65	13.1	13.1
7.45	0.000	-7.0	0.80	29.0	36.0	0.70	15.3	15.3
7.44	0.000	-6.0	1.02	30.1	36.1	0.77	17.8	17.8
7.43	0.000	-5.0	1.29	31.1	36.1	0.84	20.6	20.6
7.42	0.000	-4.0	1.64	32.1	36.2	0.93	23.8	23.7
7.40	0.001	-3.0	2.09	33.2	36.2	1.03	27.4	27.4
7.38	0.001	-2.0	2.68	34.3	36.3	1.15	31.5	31.5
7.36	0.001	-1.0	3.38	35.3	36.3	1.29	35.7	35.7
7.34	0.001	0.0	4.22	36.3	36.3	1.44	39.9	39.9
7.31	0.001	1.0	5.03	37.0	36.0	1.58	43.5	43.4
7.29	0.002	2.0	5.76	37.6	35.6	1.71	46.2	46.2
7.28	0.002	3.0	6.36	38.0	35.1	1.81	48.2	48.2
7.26	0.002	4.0	6.86	38.4	34.4	1.90	49.7	49.7
7.25	0.003	5.0	7.29	38.6	33.7	1.98	50.9	50.9
7.24	0.004	6.0	7.65	38.8	32.9	2.04	51.8	51.8
7.23	0.005	6.9	7.96	39.0	32.1	2.10	52.5	52.5
7.23	0.006	7.9	8.24	39.2	31.2	2.15	53.1	53.1
7.22	0.008	8.9	8.47	39.3	30.3	2.19	53.6	53.5
7.21	0.010	9.9	8.63	39.4	29.4	2.22	53.8	53.8
7.21	0.012	10.9	8.72	39.4	28.5	2.24	54.0	54.0
7.21	0.016	11.9	8.78	39.4	27.5	2.25	54.1	54.0
7.21	0.020	12.9	8.83	39.5	26.6	2.26	54.2	54.0
7.21	0.025	13.9	8.88	39.5	25.6	2.27	54.2	54.1
7.21	0.031	14.9	8.92	39.5	24.6	2.28	54.2	54.0
7.21	0.039	15.9	8.95	39.5	23.6	2.29	54.2	54.0
7.21	0.049	16.9	8.98	39.5	22.6	2.30	54.3	54.0
7.21	0.062	17.9	9.01	39.5	21.6	2.30	54.4	54.0
7.21	0.078	18.9	9.03	39.6	20.6	2.30	54.5	54.0
7.21	0.099	19.9	9.04	39.6	19.6	2.30	54.6	54.0

RD01MUS2 & RD07MUS2B RF characteristics data at f=400-470MHz,Vdd=7.2V

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@ f=435MHz, Vgg=3.5V (Idq=404mA)

Vdd (V)	Pi (W)	Pi (dBm)	Po (W)	Po (dBm)	Gp (dB)	Idd (A)	η_T (%)	P.A.E. (%)
7.44	0.000	-10.0	0.30	24.7	34.7	0.50	8.0	8.0
7.44	0.000	-9.1	0.37	25.7	34.8	0.53	9.5	9.5
7.43	0.000	-8.0	0.47	26.7	34.7	0.55	11.4	11.4
7.43	0.000	-7.0	0.59	27.7	34.7	0.59	13.5	13.4
7.42	0.000	-6.0	0.74	28.7	34.7	0.63	15.8	15.7
7.41	0.000	-5.0	0.93	29.7	34.6	0.68	18.4	18.4
7.40	0.000	-4.0	1.16	30.6	34.6	0.74	21.2	21.2
7.39	0.001	-3.0	1.46	31.6	34.6	0.81	24.4	24.4
7.38	0.001	-2.0	1.82	32.6	34.6	0.88	27.9	27.9
7.37	0.001	-1.0	2.27	33.6	34.6	0.97	31.8	31.7
7.35	0.001	0.0	2.78	34.4	34.5	1.06	35.6	35.6
7.34	0.001	1.0	3.35	35.3	34.3	1.16	39.4	39.4
7.32	0.002	2.0	3.96	36.0	34.0	1.26	43.0	43.0
7.31	0.002	3.0	4.62	36.6	33.7	1.36	46.6	46.5
7.29	0.002	4.0	5.26	37.2	33.2	1.45	49.7	49.6
7.28	0.003	5.0	5.88	37.7	32.7	1.54	52.4	52.4
7.26	0.004	6.0	6.47	38.1	32.1	1.63	54.8	54.7
7.25	0.005	6.9	6.99	38.4	31.5	1.70	56.6	56.6
7.24	0.006	7.9	7.45	38.7	30.8	1.77	58.1	58.1
7.23	0.008	9.0	7.87	39.0	30.0	1.83	59.4	59.3
7.22	0.010	9.9	8.20	39.1	29.2	1.88	60.3	60.2
7.22	0.012	10.9	8.48	39.3	28.4	1.93	61.0	60.9
7.21	0.016	11.9	8.70	39.4	27.5	1.96	61.5	61.4
7.21	0.020	12.9	8.86	39.5	26.6	1.99	61.8	61.7
7.20	0.025	13.9	8.99	39.5	25.6	2.01	62.2	62.0
7.20	0.031	14.9	9.08	39.6	24.7	2.02	62.4	62.2
7.20	0.039	15.9	9.15	39.6	23.7	2.03	62.7	62.4
7.20	0.049	16.9	9.19	39.6	22.8	2.03	62.8	62.5
7.20	0.061	17.8	9.22	39.6	21.8	2.04	62.9	62.5
7.20	0.076	18.8	9.24	39.7	20.8	2.04	63.0	62.5
7.20	0.096	19.8	9.25	39.7	19.8	2.04	63.0	62.4

RD01MUS2 & RD07MUS2B RF characteristics data at f=400-470MHz,Vdd=7.2V

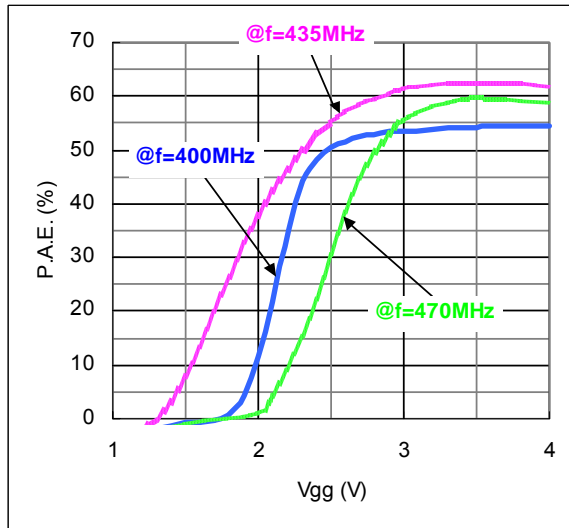
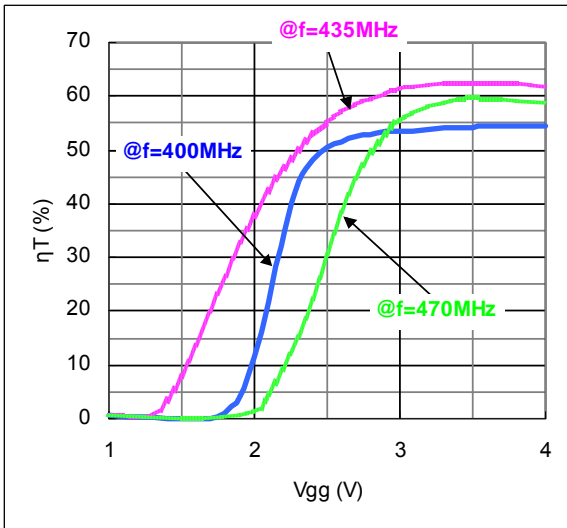
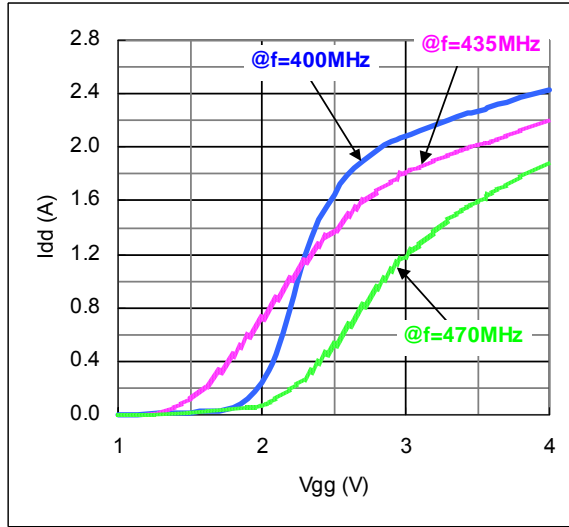
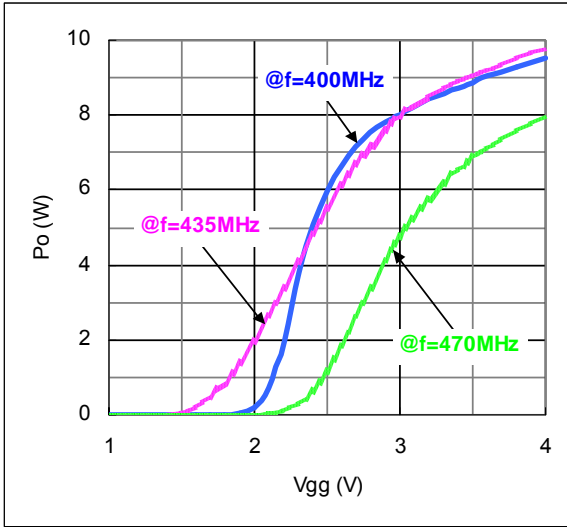
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@ f=470MHz, Vgg=3.5V (Idq=404mA)

Vdd (V)	Pi (W)	Pi (dBm)	Po (W)	Po (dBm)	Gp (dB)	Idd (A)	η_T (%)	P.A.E. (%)
7.39	0.000	-10.0	0.09	19.4	29.4	0.43	2.7	2.7
7.39	0.000	-9.0	0.11	20.4	29.4	0.44	3.4	3.4
7.39	0.000	-8.0	0.14	21.4	29.4	0.44	4.2	4.2
7.39	0.000	-7.0	0.17	22.4	29.4	0.45	5.2	5.2
7.38	0.000	-6.0	0.22	23.4	29.4	0.46	6.4	6.4
7.38	0.000	-5.0	0.27	24.3	29.3	0.47	7.8	7.8
7.38	0.000	-4.0	0.34	25.3	29.3	0.49	9.4	9.4
7.38	0.001	-3.0	0.43	26.3	29.3	0.51	11.4	11.4
7.37	0.001	-2.0	0.53	27.3	29.3	0.53	13.6	13.6
7.37	0.001	-1.0	0.67	28.2	29.3	0.56	16.2	16.2
7.36	0.001	0.0	0.83	29.2	29.2	0.60	19.0	19.0
7.36	0.001	1.0	1.04	30.2	29.2	0.64	22.2	22.2
7.35	0.002	2.0	1.30	31.1	29.2	0.69	25.8	25.8
7.34	0.002	3.0	1.62	32.1	29.1	0.75	29.6	29.6
7.33	0.002	4.0	2.02	33.0	29.1	0.81	33.8	33.8
7.32	0.003	5.0	2.48	33.9	29.0	0.89	38.2	38.2
7.31	0.004	6.0	2.99	34.8	28.8	0.97	42.4	42.3
7.29	0.005	7.0	3.55	35.5	28.5	1.05	46.3	46.2
7.28	0.006	7.9	4.10	36.1	28.2	1.13	49.6	49.5
7.27	0.008	8.9	4.63	36.7	27.7	1.21	52.5	52.4
7.25	0.010	9.9	5.11	37.1	27.2	1.29	54.7	54.6
7.24	0.012	10.9	5.55	37.4	26.5	1.36	56.5	56.3
7.23	0.016	11.9	5.94	37.7	25.8	1.42	57.7	57.6
7.22	0.020	12.9	6.29	38.0	25.1	1.49	58.6	58.4
7.21	0.025	13.9	6.61	38.2	24.3	1.55	59.2	59.0
7.20	0.031	14.9	6.88	38.4	23.5	1.61	59.5	59.2
7.19	0.039	15.9	7.13	38.5	22.6	1.66	59.6	59.3
7.19	0.049	16.9	7.34	38.7	21.8	1.72	59.5	59.1
7.18	0.061	17.9	7.52	38.8	20.9	1.77	59.2	58.7
7.17	0.077	18.9	7.68	38.9	20.0	1.82	58.7	58.2
7.16	0.098	19.9	7.80	38.9	19.0	1.87	58.2	57.5

Pout vs. Vgg characteristics

@ Vdd=7.2V, Pi=30mW (=14.77dBm), f=400MHz, 435MHz, 470MHz



Pout vs. Vgg characteristics data@ **f=400MHz**, Pi=30mW (=14.77dBm)

Vgg (V)	Idq (A)	Po (W)	Po (dBm)	Idd (A)	η_T (%)	P.A.E. (%)
1.8	0.000	0.00	5.0	0.05	0.9	0.6
1.9	0.000	0.04	15.5	0.11	4.3	4.2
2.0	0.000	0.20	23.0	0.24	11.5	11.4
2.1	0.000	0.71	28.5	0.45	21.9	21.9
2.2	0.000	2.00	33.0	0.79	35.0	35.0
2.3	0.000	3.78	35.8	1.19	44.2	44.2
2.4	0.001	5.06	37.0	1.46	48.3	48.3
2.5	0.003	5.98	37.8	1.65	50.4	50.4
2.6	0.006	6.63	38.2	1.79	51.5	51.5
2.7	0.012	7.16	38.5	1.90	52.4	52.4
2.8	0.022	7.53	38.8	1.98	52.9	52.9
2.9	0.038	7.83	38.9	2.04	53.4	53.3
3.0	0.063	8.03	39.0	2.09	53.5	53.5
3.2	0.148	8.41	39.2	2.17	53.9	53.9
3.4	0.300	8.74	39.4	2.24	54.2	54.2
3.5	0.408	8.87	39.5	2.27	54.2	54.2
3.6	0.530	9.03	39.6	2.31	54.4	54.4
3.8	0.850	9.29	39.7	2.37	54.5	54.5
4.0	1.225	9.52	39.8	2.43	54.4	54.3

@ **f=435MHz**, $P_i=30\text{mW}$ (=14.77dBm)

V _{gg} (V)	I _{dq} (A)	P _o (W)	P _o (dBm)	I _{dd} (A)	η_T (%)	P.A.E. (%)
1.4	0.000	0.01	10.9	0.05	3.2	2.9
1.5	0.000	0.07	18.3	0.12	7.7	7.6
1.6	0.000	0.20	23.0	0.21	13.4	13.3
1.7	0.000	0.45	26.6	0.32	19.8	19.8
1.8	0.000	0.83	29.2	0.44	26.3	26.2
1.9	0.000	1.36	31.3	0.58	32.5	32.5
2.0	0.000	1.92	32.8	0.71	37.5	37.5
2.1	0.000	2.62	34.2	0.86	42.3	42.3
2.2	0.000	3.35	35.3	1.00	46.4	46.4
2.3	0.000	4.10	36.1	1.14	49.8	49.8
2.4	0.001	4.80	36.8	1.26	52.7	52.7
2.5	0.003	5.50	37.4	1.39	55.2	55.2
2.6	0.006	6.13	37.9	1.49	57.0	57.0
2.7	0.012	6.70	38.3	1.59	58.5	58.5
2.8	0.022	7.15	38.5	1.67	59.6	59.6
2.9	0.038	7.58	38.8	1.74	60.5	60.4
3.0	0.063	7.95	39.0	1.80	61.3	61.3
3.2	0.148	8.50	39.3	1.90	62.0	62.0
3.4	0.300	8.91	39.5	1.98	62.4	62.4
3.5	0.408	9.07	39.6	2.02	62.5	62.5
3.6	0.530	9.21	39.6	2.05	62.4	62.4
3.8	0.850	9.51	39.8	2.12	62.3	62.3
4.0	1.225	9.78	39.9	2.20	61.9	61.9

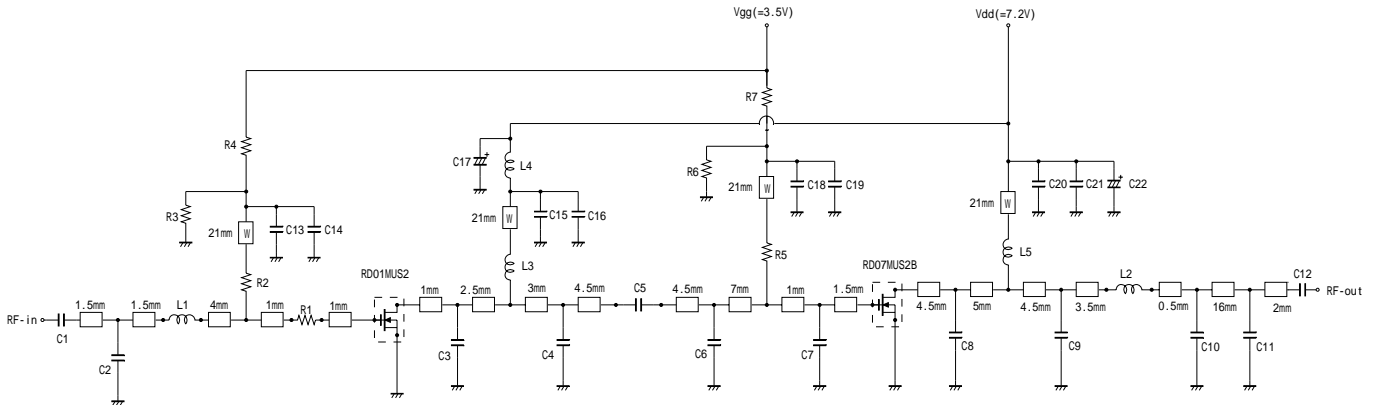
@ **f=470MHz**, $P_i=30\text{mW}$ (=14.77dBm)

V _{gg} (V)	I _{dq} (A)	P _o (W)	P _o (dBm)	I _{dd} (A)	η_T (%)	P.A.E. (%)
2.0	0.000	0.01	7.8	0.06	1.3	1.1
2.1	0.000	0.04	15.7	0.11	4.6	4.4
2.2	0.000	0.12	20.7	0.18	9.0	9.0
2.3	0.000	0.30	24.7	0.27	15.2	15.2
2.4	0.001	0.61	27.8	0.38	22.2	22.2
2.5	0.003	1.13	30.5	0.51	30.5	30.4
2.6	0.006	1.82	32.6	0.66	38.3	38.3
2.7	0.012	2.60	34.2	0.81	44.7	44.7
2.8	0.022	3.37	35.3	0.95	49.4	49.4
2.9	0.038	4.09	36.1	1.07	52.9	52.9
3.0	0.063	4.73	36.8	1.19	55.5	55.5
3.2	0.148	5.74	37.6	1.37	58.0	58.0
3.4	0.300	6.53	38.2	1.53	59.3	59.3
3.5	0.408	6.85	38.4	1.60	59.6	59.6
3.6	0.530	7.12	38.5	1.66	59.5	59.5
3.8	0.850	7.58	38.8	1.78	59.1	59.1
4.0	1.225	7.97	39.0	1.89	58.7	58.7

RD01MUS2 & RD07MUS2B RF characteristics data at f=400-470MHz, Vdd=7.2V

- AN-UHF-097-B-

Equivalent circuit (@f=400 to 470MHz)



Note: Board material- Glass-Epoxy Substrate
 Micro strip line width=1.3mm/50ohm, er:4.8, t=0.8mm
 W: Line width=1.0mm

Parts Type		Value	Type name	Vender
Capacitor	C1	100pF	GRM2162C1H101GD01E	Murata Manufacturing Co., Ltd.
	C2	12pF	GRM2162C1H120GD01E	Murata Manufacturing Co., Ltd.
	C3	22pF	GRM2162C1H220GD01E	Murata Manufacturing Co., Ltd.
	C4	8pF	GRM2162C1H8R0DD01E	Murata Manufacturing Co., Ltd.
	C5	39pF	GRM2162C1H390GD01E	Murata Manufacturing Co., Ltd.
	C6	20pF	GRM2162C1H200GD01E	Murata Manufacturing Co., Ltd.
	C7	54pF	GRM2162C1H540GD01E	Murata Manufacturing Co., Ltd.
	C8	24pF	GRM2162C1H240GD01E	Murata Manufacturing Co., Ltd.
	C9	20pF	GRM2162C1H200GD01E	Murata Manufacturing Co., Ltd.
	C10	3pF	GRM2163C1H3R0CD01E	Murata Manufacturing Co., Ltd.
	C11	3pF	GRM2163C1H3R0CD01E	Murata Manufacturing Co., Ltd.
	C12	100pF	GRM2162C1H101GD01E	Murata Manufacturing Co., Ltd.
	C13	1000pF	GRM216R11H102KA01E	Murata Manufacturing Co., Ltd.
	C14	10000pF	GRM216R11H103KA01E	Murata Manufacturing Co., Ltd.
C15	1000pF	GRM216R11H102KA01E	Murata Manufacturing Co., Ltd.	
C16	10000pF	GRM216R11H103KA01E	Murata Manufacturing Co., Ltd.	
C17	22μF	A0603	NICHICON CORPORATION	
C18	1000pF	GRM216R11H102KA01E	Murata Manufacturing Co., Ltd.	
C19	10000pF	GRM216R11H103KA01E	Murata Manufacturing Co., Ltd.	
C20	1000pF	GRM216R11H102KA01E	Murata Manufacturing Co., Ltd.	
C21	10000pF	GRM216R11H103KA01E	Murata Manufacturing Co., Ltd.	
C22	22μF	A0603	NICHICON CORPORATION	
Resistance	R1	12 OHM	RPC05-120	Taiyosha Electric Co.,Ltd.
	R2	1K OHM	RPC10-102	Taiyosha Electric Co.,Ltd.
	R3	56K OHM	RPC05-563	Taiyosha Electric Co.,Ltd.
	R4	20K OHM	RPC05-203	Taiyosha Electric Co.,Ltd.
	R5	4.7K OHM	CR1/10-472JB	Hokuriku Electric Industry Co.,Ltd.
	R6	15K OHM	RPC05-153	Taiyosha Electric Co.,Ltd.
	R7	20K OHM	RPC05-203	Taiyosha Electric Co.,Ltd.
Inductance	L1	8.2nH(Chip Inductor)	LQG11A8N2S00	Murata Manufacturing Co., Ltd.
	L2	6.6nH Enameled wire 2Turns, Diameter:0.23mm,φ1.66mm (the out side diameter)	2302S	Yoneda Processing Place Co.,Ltd.
	L3	31.0nH Enameled wire 6Turns, Diameter:0.23mm,φ1.66mm (the out side diameter)	2306C	Yoneda Processing Place Co.,Ltd.
	L4	6.6nH Enameled wire 2Turns, Diameter:0.23mm,φ1.66mm (the out side diameter)	2302S	Yoneda Processing Place Co.,Ltd.
	L5	31.0nH Enameled wire 6Turns, Diameter:0.23mm,φ1.66mm (the out side diameter)	2306C	Yoneda Processing Place Co.,Ltd.

